#### Philips Components-Signetics

853-0130
86487
November 11, 1986
Product Specification

# 82S181 / 82S181A 8K-bit TTL bipolar PROM

#### DESCRIPTION

The 82S181 and 82S181A are field programmable, which means that custom patterns are immediately available by following the Signetics Generic I fusing procedure. The 82S181 and 82S181A are supplied with all outputs at logical Low. Outputs are programmed to a logic High level at any specified address by fusing the Ni-Cr link matrix.

This device includes on-chip decoding and four Chip Enable inputs for ease of memory expansion. It features 3-State outputs for optimization of word expansion in bused organizations.

Ordering information can be found on the following page.

The 82S181 and 82S181A devices are also processed to military requirements for operation over the military temperature range. For specifications and ordering information consult the Signetics Military Data Handbook.

#### **FEATURES**

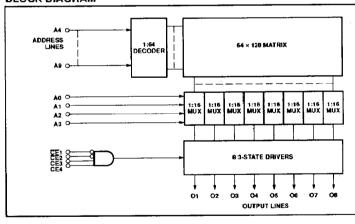
- · Address access time:
  - N82S181: 70ns max
  - N82S181A: 55ns max
- Power dissipation: 76µW/bit typ
- Input loading: −100µA max
- On-chip address decoding
- Four Chip Enable inputs
- Outputs: 3-State
- No separate fusing pins
- Unprogrammed outputs are Low level
- Fully TTL compatible

#### **APPLICATIONS**

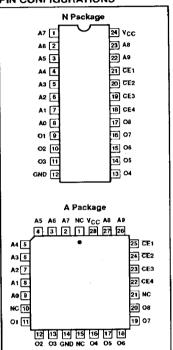
- Prototyping/volume production
- Sequential controllers
- Microprogramming
- Hardwired algorithms
- Control store
- Random logic

- Code conversion

# **BLOCK DIAGRAM**



# PIN CONFIGURATIONS



# 8K-bit TTL bipolar PROM (1024 × 8)

# 82S181 / 82S181A

# ORDERING INFORMATION

DESCRIPTION	ORDER CODE
24-Pin Plastic Dual-In-Line 600mil-wide	N82S181 N, N82S181A N
28-Pin Plastic Leaded Chip Carrier 450mil-square	N82S181 A, N82S181A A

# ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	RATING	UNIT	
Vcc	Supply voltage	+7.0	V <sub>DC</sub>	
V <sub>IN</sub>	Input voltage	+5.5	V <sub>DC</sub>	
Vo	Output voltage Off-State	+5.5	V <sub>DC</sub>	
Tamb	Operating temperature range	0 to +75	.€	
T <sub>stg</sub>	Storage temperature range	-65 to +150	°C	

# DC ELECTRICAL CHARACTERISTICS

0°C ≤ T<sub>amb</sub>≤ +75°C, 4.75V ≤ V<sub>CC</sub> ≤ 5.25V

			LIMITS				
SYMBOL	PARAMETER	TEST CONDITIONS <sup>1,2</sup>	Min	Typ <sup>3</sup>	Мах	UNIT	
Input volt	age <sup>2</sup>						
V <sub>IL</sub>	Low				. 0.8	٧	
ViH	High		2.0			٧	
$V_{IC}$	Clamp	I <sub>IN</sub> = -12mA		-0.8	-1.2	V	
Output vo	ltage <sup>2</sup>						
		CE1,2 = Low, CE3,4 = High					
Vol	Low	l <sub>OUT</sub> = 9.6mA			0.45	٧	
V <sub>OH</sub>	High	I <sub>OUT</sub> = -2.0mA	2.4			V	
Input curr	rent <sup>1</sup>				•		
1,,	Low	$V_{ N} = 0.45V$			-100	μΑ	
l <sub>iH</sub>	High	$V_{IN} = 5.5V$		i	40	μΑ	
Output cu	urrent <sup>1</sup>						
loz	Hi-Z state	CE1,2 = High, CE3,4 = Low, V <sub>OUT</sub> = 5.5V			40	μΑ	
		CE1,2 = High, CE3,4 = Low, V <sub>OUT</sub> = 0.5V		1	-40	μΑ	
los	Short circuit <sup>4</sup>	CE1,2 = Low, CE3,4 = High, V <sub>OUT</sub> = 0V High stored	$\overline{CE}1.2 = \text{Low}, CE3.4 = \text{High}, V_{OUT} = 0V$ -15 -70				
Supply cu	ırrent <sup>5</sup>						
lcc		V <sub>CC</sub> = 5.25V		125	175	mA	
Capacitar	nce						
		CE1,2 = High, V <sub>CC</sub> = 5.0V					
CIN	Input	$V_{1N} = 2.0V$		5		pF	
Caut	Output	V <sub>OUT</sub> = 2.0V		8		pF	

#### NOTES:

- NOTES:

  1. Positive current is defined as into the terminal referenced.
  2. All voltages with respect to network ground
  3. Typical values are at V<sub>CC</sub> = 5V, T<sub>amb</sub> = +25°C.
  4. Duration of the short circuit should not exceed 1 second.
  5. Measured with all inputs grounded and all outputs open.

# 8K-bit TTL bipolar PROM (1024 $\times$ 8)

# 82S181 / 82S181A

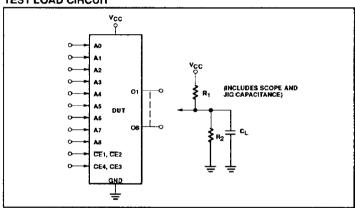
AC ELECTRICAL CHARACTERISTICS  $R_1 = 470\Omega, \ R_2 = 1 k\Omega, \ C_L = 30 pF, \ 0^{\circ}C \le T_{amb} \le +75^{\circ}C, \ 4.75 V \le V_{CC} \le 5.25 V$ 

SYMBOL	PARAMETER		TO FROM	N82S181		N82S181A				
		то		Min	Typ1	Max	Min	Typ¹	Max	UNIT
Access tin	ne <sup>2</sup>									
1 <sub>AA</sub>		Output	Address		50	70		45	55	ns
t <sub>CE</sub>		Output	Chip Enable		25	40		25	40	ns
Disable tin	ne <sup>3</sup>									
t <sub>CD</sub>		Output	Chip Disable		25	40		25	40	ns

# NOTES:

- NOTes: 1. Typical values are  $V_{CC}$  = 5V,  $T_{amb}$  = +25°C. 2. Tested at an address cycle time of 1µs. 3. Measured at a delta of 0.5V from Logic Level with  $R_1$  = 750 $\Omega$ ,  $R_2$  = 750 $\Omega$  and  $C_L$  = 5pF.

# TEST LOAD CIRCUIT



# **VOLTAGE WAVEFORM**

